Preliminary Development of Selenium-Silicon Tandem Solar Cells

Charif Tamin^{1, *}, Céline Chevalier¹, Alain Fave²

¹CNRS, Ecole Centrale de Lyon, INSA Lyon, Université Claude Bernard Lyon 1, CPE Lyon, INL, UMR5270, 69100 Villeurbanne, France

² INSA Lyon, Ecole Centrale de Lyon, CNRS, Université Claude Bernard Lyon 1, CPE Lyon, INL, UMR5270, 69100 Villeurbanne, France

Email : <u>charif.tamin@cnrs.fr</u>

Abstract

Tandem solar cells (TSCs) represent an innovative approach in photovoltaic (PV) technology by stacking multiple cells with varying bandgaps, which improves light collection and leads to higher efficiencies. Silicon-based TSCs, combining silicon with wide-bandgap materials, offer a promising pathway to achieving high efficiency at lower costs. Notably, Si-perovskite tandem cells have recently reached record efficiencies of 33.9 %, though challenges such as long-term stability and scalability still need to be addressed for industrial-scale implementation.

Selenium (Se), one of the oldest photovoltaic materials, is an intriguing option for use in tandem structures with silicon. This non-toxic and abundant chalcogenide has attracted attention due to its high absorption coefficient ($\sim 10^5$ cm⁻¹), wide bandgap, and compatibility with low-temperature deposition. This study presents our preliminary results on the development of selenium-silicon tandem solar cells. Planar passivated emitter and rear contact (PERC) silicon (Si) solar cells, with indium tin oxide (ITO) as a transparent front contact, and bifacial selenium (Se) solar cells were prepared separately and physically bonded using a custom-designed clamping tool. The observed tandem effect includes an open-circuit voltage (Voc) of 1.17 V and an efficiency exceeding 5%. Currently, monolithic cells are under development to enable the direct growth of the Se top cell on the Si bottom cell with a tunnel junction, aiming to minimize losses and improve overall efficiency.



Figure 1 Schematic Representation of the Selenium-Silicon Tandem Solar Cell Structure (a) and the Corresponding Current-Voltage (J-V) Curve